( )]TJ ET BT 10.56 0 0 10.56 0 0 Tm /1F8 1 Tf 0 0 0 sc 0 0 0 SC 0 Tr15.586 3.9836 TD [( )]TJ ET BT 10.56 0 0 10

TO-252 N

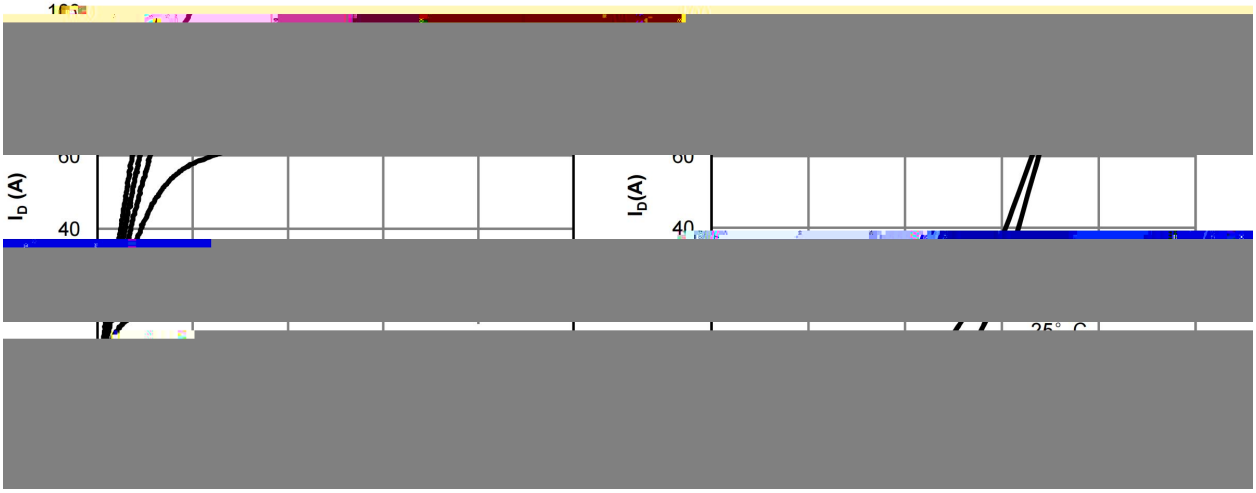
N-CHANNEL MOSFET in a TO-252

参数 Parameter	符号 Symbol	数值 Rating	单位 Unit
Drain-Source Voltage	V_{DS}	100	V
Drain Current - Continuous	I_D	68	A
Drain Current – Pulsed	I_{DM}	156	A

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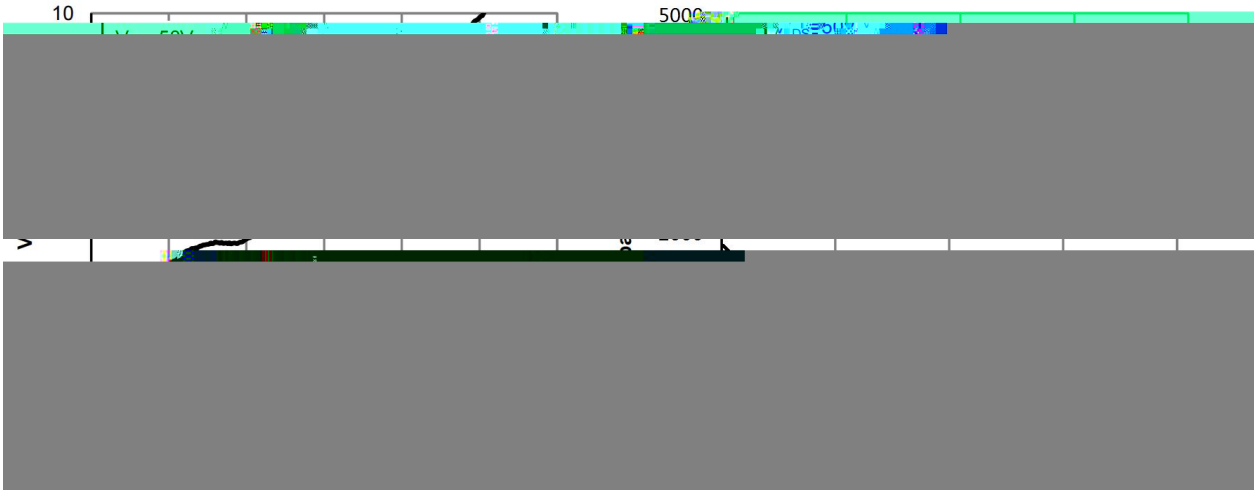
/ Electrical Characteristic Curve

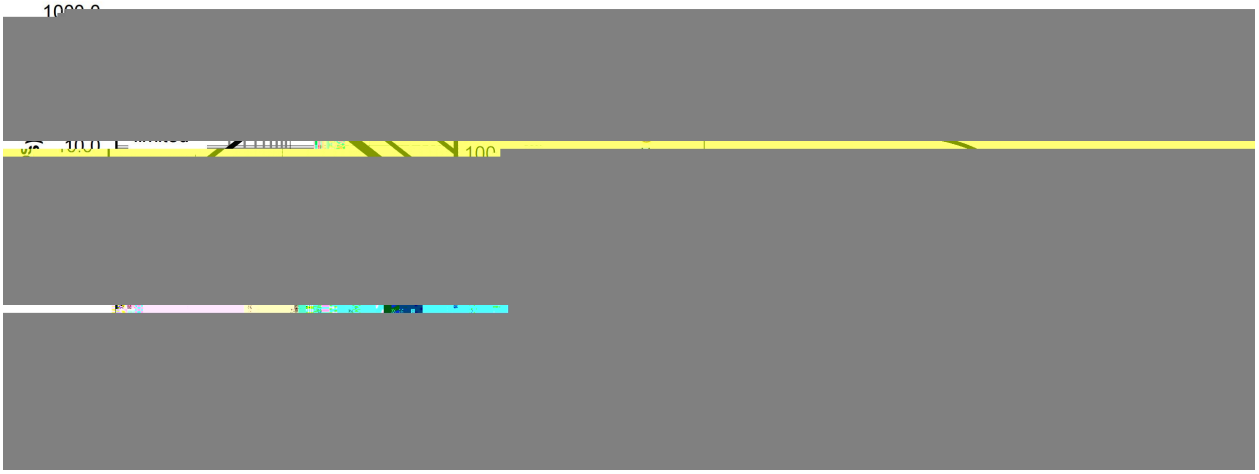


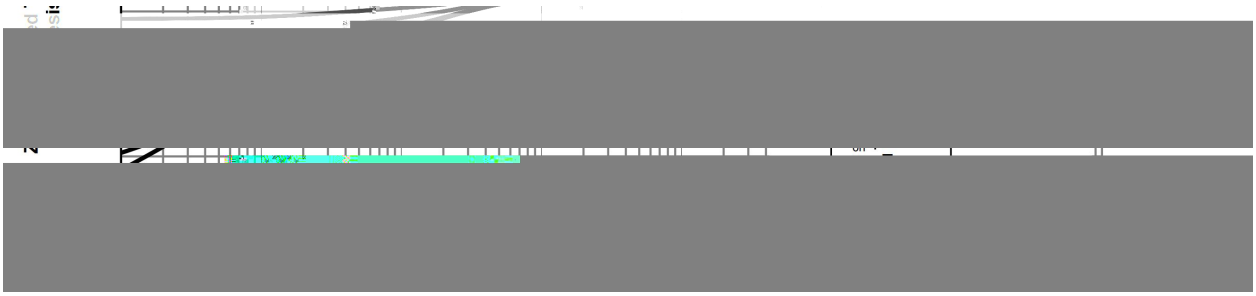




/ Electrical Characteristic Curve

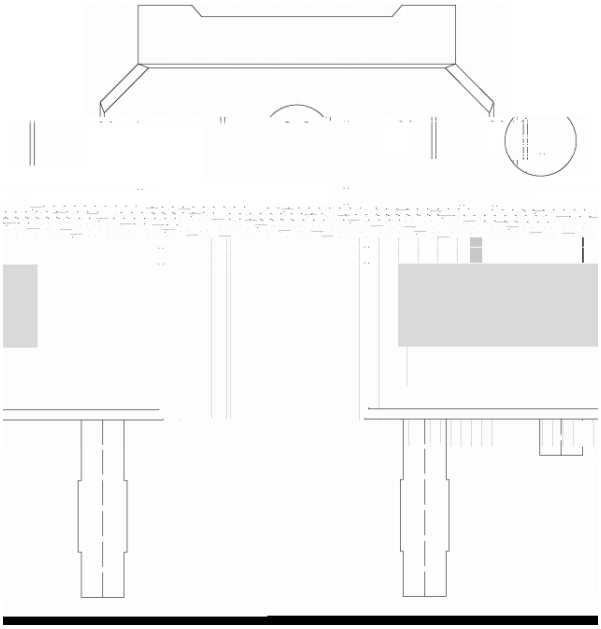






BRCS

/ Marking Instructions



( ) / Temperature Profile for IR Reflow Soldering(Pb-Free)

Note:

1	150	180	60	90sec;	1.P